Special Issue

Design and Application of 3D Semiconductor Devices

Message from the Guest Editors

The demand for modern semiconductor technology is unprecedented, driven by the insatiable thirst for faster, more powerful electronic devices across various industries. From smartphones to supercomputers, the relentless pursuit of devices necessitates breakthroughs in semiconductor technology. However, this pursuit is accompanied by formidable challenges, particularly in power delivery and transistor design. One significant challenge lies in optimizing power delivery, especially through innovative approaches like backside power delivery (BPD). Moreover, the evolution of smaller and more efficient devices hinges on advancements in transistor technology, particularly complementary fieldeffect transistors (cFETs). These transistors offer superior performance and energy efficiency, which are critical for meeting the demands of modern electronics. Additionally, leveraging low-dimensional channel materials presents a promising avenue for enhancing transistor performance. By harnessing the unique properties of these materials, researchers aim to overcome current limitations and unlock new possibilities for semiconductor technology.

Guest Editors

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Electronics is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guest-edited by leading experts in selected topics of interest.

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